

Supplementary Information for

Development of Fin-LEDs for Next-generation Inorganic Displays using Face-selective Dielectrophoretic Assembly

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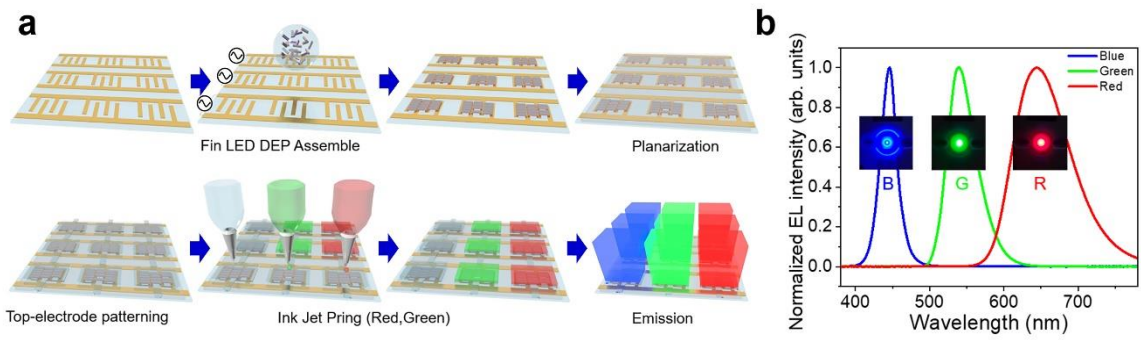
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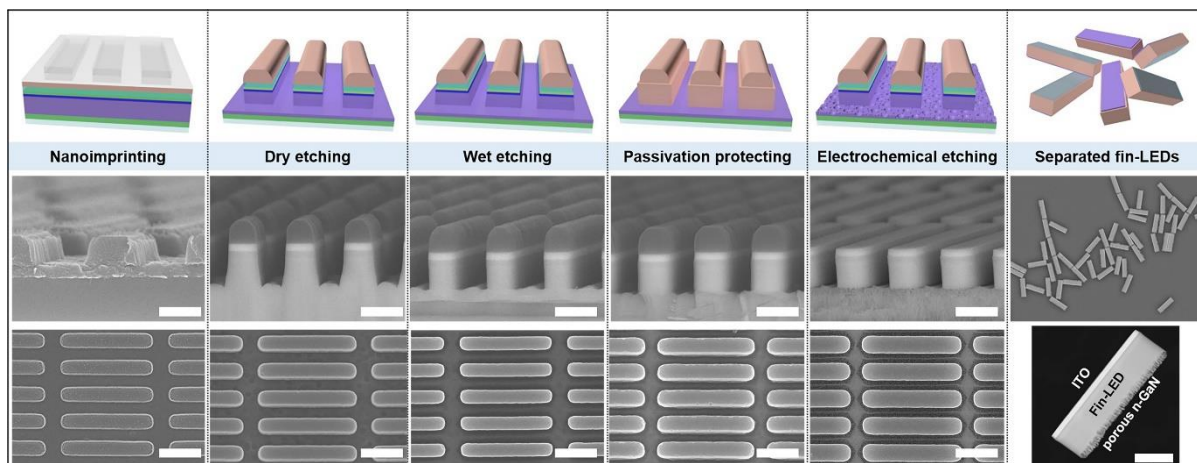
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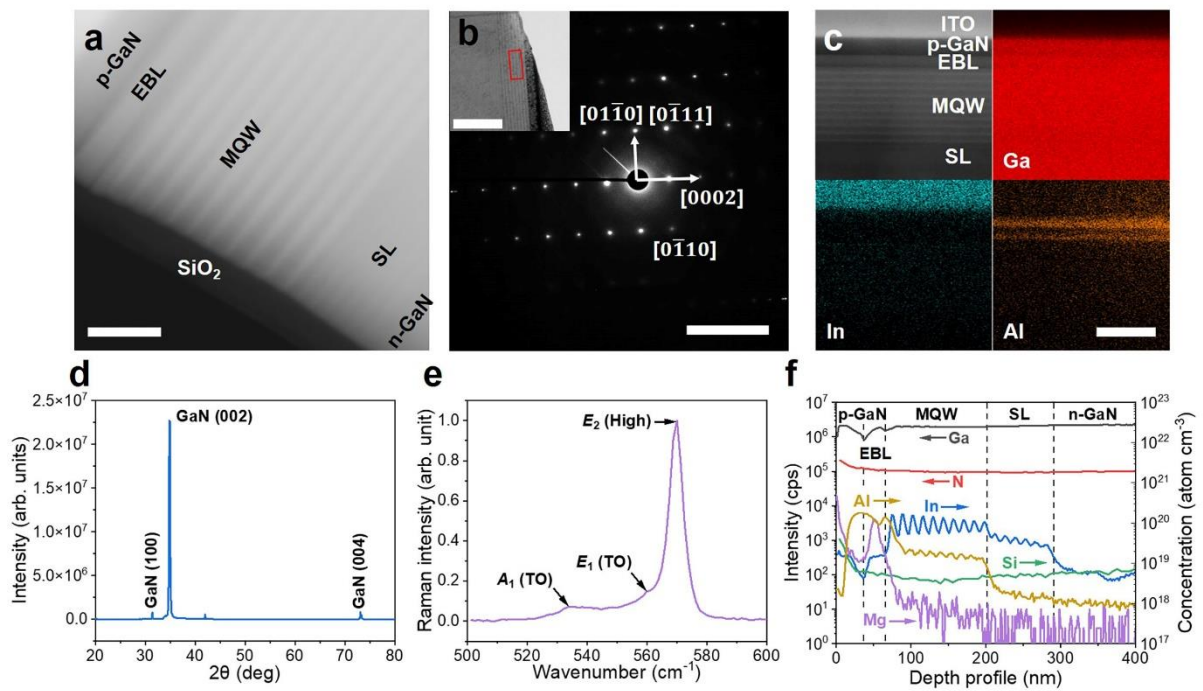
Supplementary Fig. 1 | Schematic of implementing a full-color fin-LED Display

a Schematic of full-color fin-LED display. **b** Fin-LED color conversion RGB EL spectrum (Blue: fin-LED, Green: fin-LED@InP QDs color film, Red: fin LED@R6832 phosphor color film).



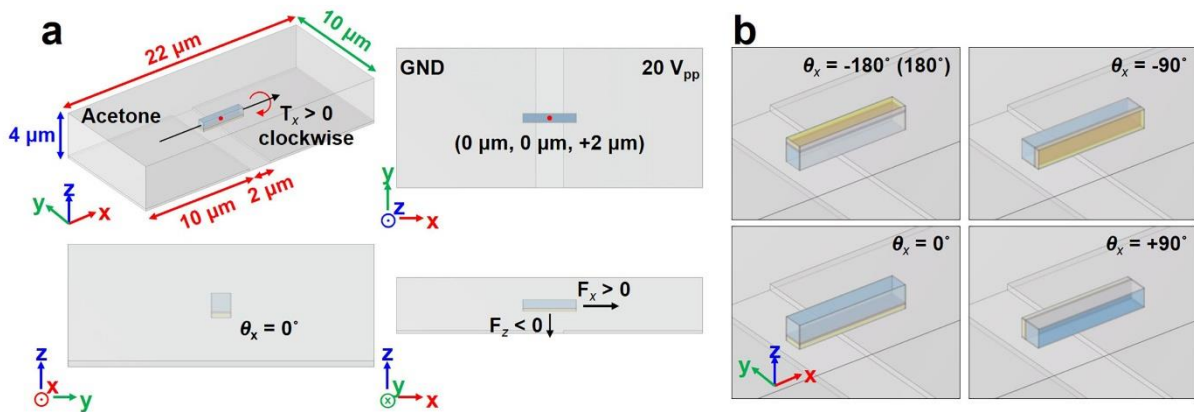
Supplementary Fig. 2 | Schematic diagram of fin-LED fabrication process

Electron microscopy images of each step of fabrication process of individually separated fin-LED. All scale bars represent 1 μm .



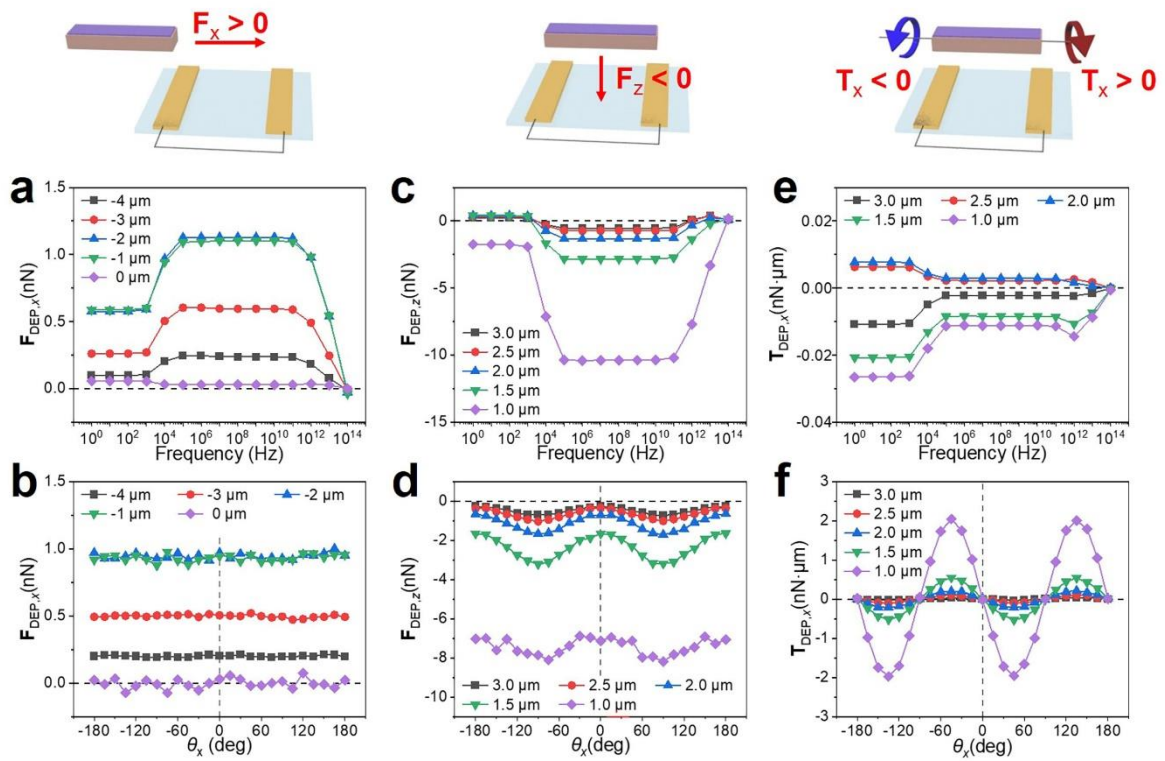
Supplementary Fig. 3 | Additional analysis data for individually separated fin-LED

a High-angle annular dark-field (HAADF)-STEM image of ITO/p-GaN/MQW/n-GaN@SiO₂ structured fin-LED. **b** Selected area electron diffraction (SAED) patterns of MQW of fin-LED. (Inset TEM image of fin-LED) **c** Energy-dispersive X-ray spectroscopy (EDX) images of fin-LED. **d** X-ray diffraction (XRD) spectrum of fin-LED. **e** Raman spectrum of fin-LED. **f** Dynamic-secondary ion mass spectroscopy (SIMS) depth profiles of fin-LED. EBL, electron blocking layer; MQW, multiple quantum well; SL, superlattice.



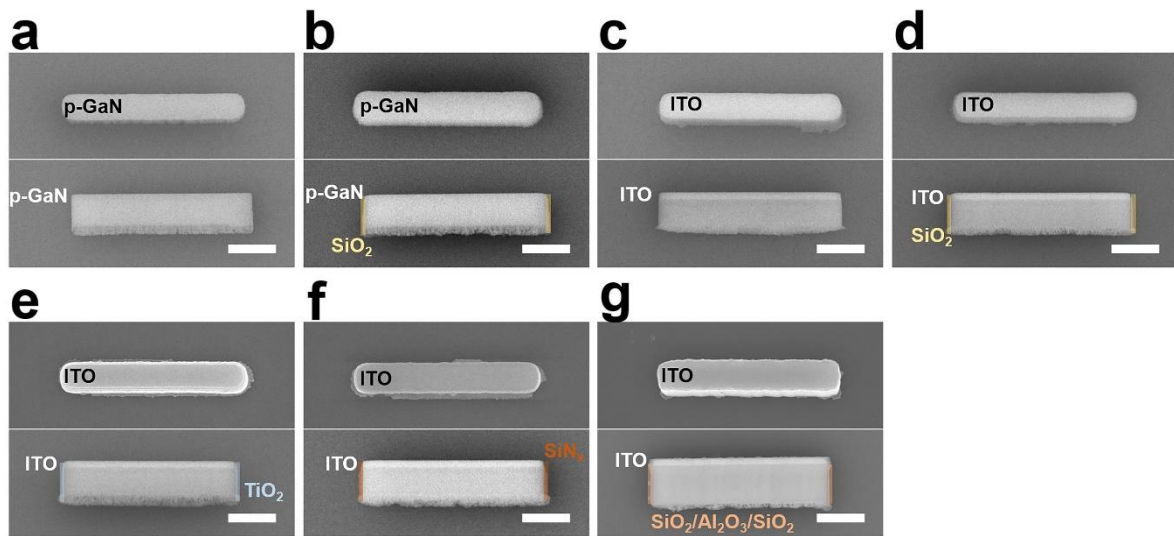
Supplementary Fig. 4 | Schematic of 3D model for finite element simulation (FEM)

a A pair of 10 μm × 10 μm electrodes were placed on the bottom with a 2 μm gap on the entire domain size of 22 μm × 10 μm × 4 μm. The center coordinates of a GaN-based light-emitting diode (LED) were arranged to be (0 μm, 0 μm, +2 μm). The remaining area except for the electrodes and LED was composed of solvent (acetone). **b** Schematic diagram according to x-axis rotation angle of the LED. It was set to 0° when the n-GaN was facing upward. The n- and p-GaN, ITO, and the shell layer on the side of the LED (SiO₂) are expressed in blue, red, yellow, and white, respectively.



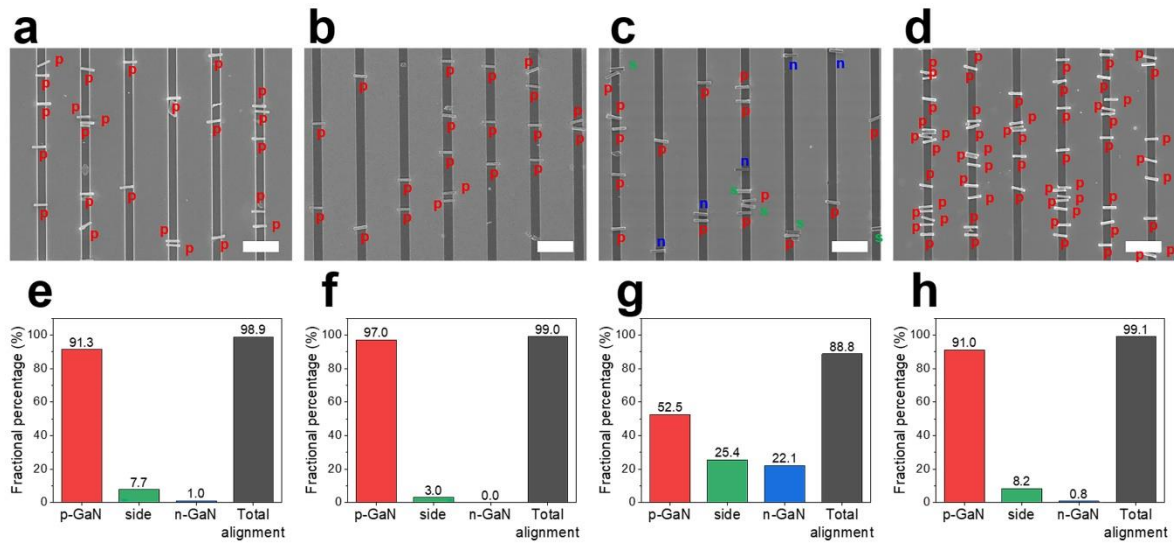
Supplementary Fig. 5 | FEM simulation results of ITO/fin-LED@SiO₂ LED

a,b The x-axis dielectrophoretic (DEP) force as a function of frequency of the LED with an x-angle of 0° and as a function of x-angle of the LED with a frequency of 10 kHz when the central coordinates of LED changed from (−4 μm, 0 μm, +2 μm) to (0 μm, 0 μm, +2 μm). **c,d** The z-axis DEP force as a function of frequency of the LED with an x-angle of 0° and as a function of x-angle of the LED with a frequency of 10 kHz when the central coordinates of LED changed from (0 μm, 0 μm, +3 μm) to (0 μm, 0 μm, +1 μm). **e,f** The x-axis DEP torque as a function of frequency of the LED with an x-angle of 0° and as a function of x-angle of the LED with a frequency of 10 kHz when the central coordinates of LED changed from (0 μm, 0 μm, +3 μm) to (0 μm, 0 μm, +1 μm).



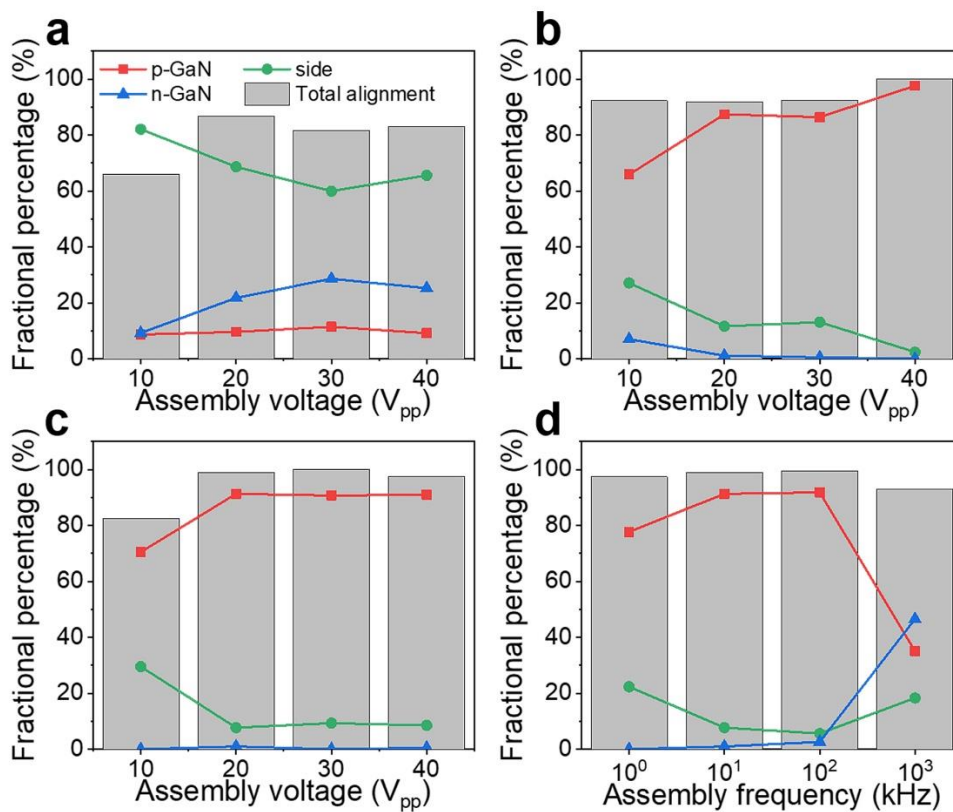
Supplementary Fig. 6 | SEM images of fin-LED with different structures

The upper images are the top view of the fin-LEDs and the lower images are the cross-sectional view of the fin-LEDs obtained in backscattered electron (BSE) mode. **a** fin-LED. **b** fin-LED@SiO₂. **c** ITO/fin-LED. **d** ITO/fin-LED@SiO₂. **e** ITO/fin-LED@TiO₂. **f** ITO/fin-LED@SiN_x. **g** ITO/fin-LED@SiO₂/Al₂O₃/SiO₂. All scale bars represent 1 μm.



Supplementary Fig. 7 | Self-assembly results of different structured fin-LED by DEP force

a–d SEM image of ITO/fin-LED@SiO₂, ITO/fin-LED@SiN_x, ITO/fin-LED@TiO₂, and ITO/fin-LED@SiO₂/Al₂O₃/SiO₂ structures. To align the fin-LEDs of all structures, a sinusoidal function with a voltage of 20 V_{pp} and a frequency of 10 kHz was applied to the electrodes. To indicate the contact surface between the fin-LEDs and electrodes, different colored letters were marked on the individual LEDs: red p, p-GaN contact; blue n, n-GaN contact; green s, side contact. All scale bars represent 10 μm. **e–h** Fractional ratio of different contact of ITO/fin-LED@SiO₂, ITO/fin-LED@SiN_x, ITO/fin-LED@TiO₂, and ITO/fin-LED@SiO₂/Al₂O₃/SiO₂ structures. All scale bars represent 10 μm.



Supplementary Fig. 8 | Fractional ratio of different ITO/fin-LED@SiO₂ with solvent

a–c Fractional ratio in hexane, isopropyl alcohol (IPA) and acetone depending on the voltage with an applied frequency of 10 kHz (sinusoidal wave function). **d** The ratio in acetone depending on the frequency with an applied voltage of 20 V_{pp}. All legends in the graphs are identical to those expressed in **a**.

C

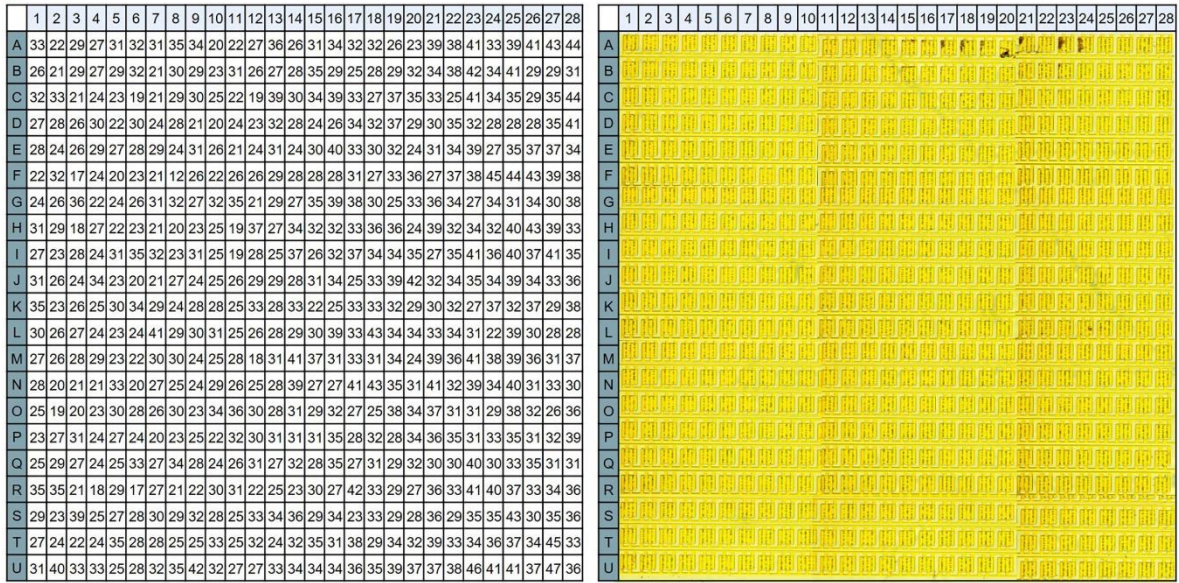
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C	44	40	42	33	39	30	33	29	36	40	36	26	40	35	41	34	38	44	37	34	39	35	29	33	39	38	35	33
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I	41	28	33	43	35	32	35	30	37	35	37	32	29	36	34	33	39	28	38	30	32	29	39	36	31	33	35	35
J	31	35	29	27	31	25	41	26	31	29	32	23	32	24	22	31	30	37	36	28	22	35	34	36	38	32	30	31
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M	32	27	30	30	30	28	26	30	34	27	31	30	28	29	29	24	32	27	27	32	32	37	31	34	37	28	31	37
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Q	30	19	21	17	20	23	21	22	28	29	26	21	22	23	22	22	25	30	30	26	26	27	31	29	31	27	33	22
R	31	25	23	26	23	27	22	24	30	31	29	22	21	27	34	31	31	24	19	30	26	27	31	29	31	27	33	22
S	33	29	27	36	33	22	27	33	27	30	25	26	32	28	32	35	36	29	23	31	31	28	32	34	30	33	30	34
T	32	28	26	29	24	28	29	18	27	28	32	28	25	30	30	25	30	33	31	32	30	31	30	26	27	35	36	36
U	39	26	22	29	22	27	26	22	23	28	30	33	28	35	28	28	28	29	25	21	34	24	32	24	31	28	27	41

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C	44	40	42	33	39	30	33	29	36	40	36	26	40	35	41	34	38	44	37	34	39	35	29	33	39	38	35	33
D	35	31	35	43	42	37	33	39	36	40	32	32	35	33	35	32	38	41	37	33	31	36	32	28	34	37	37	34
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H	43	26	28	23	33	34	32	31	31	40	30	33	30	36	32	42	37	30	36	34	34	35	32	34	32	33	30	25
I	41	28	33	43	35	32	35	30	37	35	37	32	29	36	34	33	39	28	38	30	32	29	39	36	31	33	35	35
J	31	35	29	27	31	25	41	26	31	29	32	23	32	24	22	31	30	37	36	28	22	35	34	36	38	32	30	31
K	32	23	26	28	23	32	29	27	27	27	25	29	30	22	27	33	26	33	30	28	31	32	36	35	35	33	31	26
L	29	27	31	27	33	19	27	24	28	23	26	25	30	29	30	28	29	32	33	29	34	30	30	36	40	38	28	31
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N	34	26	15	30	25	30	23	30	33	31	34	29	31	29	36	32	35	33	34	32	33	35	37	35	45	26	36	
O	29	24	21	19	23	29	27	28	22	22	32	29	26	25	31	33	27	26	34	31	36	30	33	36	36	37	40	27
P	22	20	21	28	19	26	25	24	17	28	26	31	22	24	33	32	31	25	27	22	37	29	38	32	35	36	29	25
Q	30	19	21	17	20	23	21	22	28	29	26	21	22	23	22	22	25	30	30	26	26	27	31	29	31	27	33	22
R	31	25	23	26	23	27	22	24	30	31	29	22	21	27	34	31	31	24	19	30	26	27	31	29	31	27	33	22
S	33	29	27	36	33	22	27	33	27	30	25	26	32	28	32	35	36	29	23	31	31	28	32	34	30	33	30	34
T	32	28	26	29	24	28	29	18	27	28	32	28	25	30	30	25	30	33	31	32	30	31	30	26	27	35	36	36
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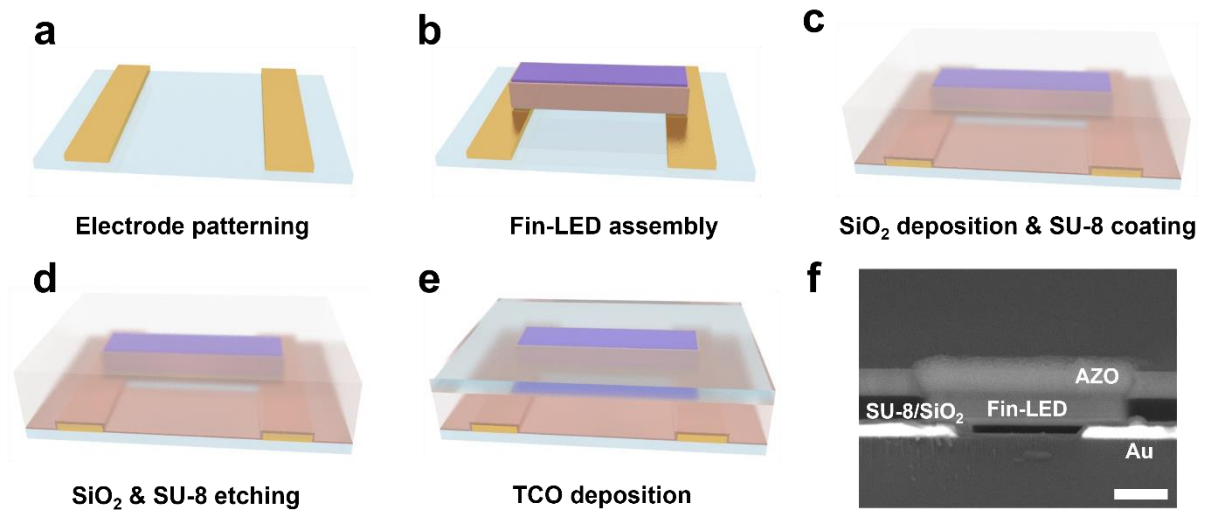
d

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A	39	33	34	38	35	34	48	47	41	46	40	40	41	48	52	43	40	23	28	46	58	54	48	51	41	42	49	52
B	32	39	36	30	21	23	23	32	27	36	32	36	39	32	29	26	20	32	27	45	34	32	34	43	36	36	38	47
C	31	34	24	20	23	30	27	18	25	32	26	32	25	28	33	27	29	29	30	31	29	38	29	32	31	40	33	46
D	29	27	17	29	24	24	24	19	20	23	32	21	31	22	21	21	32	35	45	36	45	52	34	29	26	27	34	50
E	35	27	27	22	27	27	32	16	28	31	31	31	34	24	27	32	37	39	48	39	39	53	32	30	28	38	36	39
F	37	32	22	23	29	22	19	30	24	22	34	29	29	33	25	32	25	38	44	28	29	28	27	18	32	30	34	42
G	36	32	24	28	28	27	22	23	31	18	17	32	32	26	24	20	37	22	32	25	21	33	34	29	28	27	40	53
H	29	23	27	24	58	24	27	23	24	31	29	19	28	31	29	23	25	25	21	21	20	29	36	27	18	28	36	37
I	25	31	32	44	52	30	25	27	25	26	23	25	22	28	25	23	22	28	32	20	34	30	32	25	29	33	42	29
J	39	35	33	28	29	32	29	16	20	33	22	28	24	22	21	23	15	24	29	28	20	22	25	29	25	19	26	40
K	38	29	29	24	24	30	22	27	30	17	29	46	37	27	25	25	29	27	59	30	37	27	25	20	25	26	23	36
L	29	30	26	25	24	33	30	35	24	28	22	32	33	22	20	34	35	49	58	27	23	26	25	31	22	30	28	31
M	32	29	34	18	26	21	23	30	26	26	20	23	35	25	32	40	32	34	34	32	33	43	32	39	29	35	34	52
N	36	19	33	24	30	24	24	22	29	26	19	23	30	31	34	58	50	35	28	24	28	31	34	33	27	42	46	46
O	39	25	23	31	31	23	25	19	20	29	23	25	19	31	37	27	32	37	3									

e



Supplementary Fig. 9 | Optical microscope image of five fin-LED array devices with 588 subpixels
a Panel-1, mean: 30.47, standard deviation (σ): 4.16. **b** Panel-2, mean: 31.06, σ : 6.40. **c** Panel-3, mean: 31.27, σ : 5.35. **d** Panel-4, mean: 30.44, σ : 7.97. **e** Panel-5, mean :30.50, σ :5.82 (Total subpixel: 2,940, Assembly accuracy: 99.93%).



Supplementary Fig. 10 | Schematics of fabrication of EL device based on the fin-LEDs

a Fabrication of electrode. **b** Fin-LEDs DEP assembly. **c** SU-8 planarization coat & SiO₂ anchor deposition. **d** TCO deposition. **e** SEM image of fin-LEDs EL Device. Scale bar represents 1 μm

Assembly	Transfer method	Chip size (μm^2)	Chip cost	Transfer Cost	Transfer speed	Transfer yield (%)	Ref	
Pick up	Elastomer stamp	~1,256.00	Middle	High	1M hr ⁻¹	99.50	[1,2]	
	Laser	~1.00	Low~Middle	Middle~High	100M hr ⁻¹	99.80	[1,2]	
Fluidic assembly	Wave energy	~1,256.00	Middle	Middle	NR	97.00	[3]	
	Gravity and capillary force	~1,256.00	Middle	Middle	1M hr ⁻¹	99.90	[4]	
	Vander walls force	1,256.00	Middle	Middle	54K hr ⁻¹	99.99	[5]	
	Molten solder	706.50	Middle	Middle	1M hr ⁻¹	99.88	[6]	
	magnetic-force-assisted dielectrophoretic self-assembly technology	~980.20	Middle	Middle	NR	99.50	[7]	
	Dielectricphoresis		~0.19	Low	Low	NR	99.98	[8~13]
			2.80	Low	Low	1M hr ⁻¹	99.93	Our works

Supplementary Table 1 | Comparison for micro-LED mass transfer method

Volume (μm^2) Shape	Area of MQW (μm^2)	Orientation selective ratio (%)	Aligned direction	Wavelength (nm)	Brightness (cd m^{-2})	EQE (%)	Ref
0.49, rod	0.20	NR	Horizontal	515	2,130 (20V)	NR	[8]
0.66, rod	0.23	74.4	Horizontal	515	NR	NR	[9]
0.97, rod	0.22	NR	Horizontal	448	NR	8.9~20.2	[10]
1.32, rod	0.26	NR	Horizontal	445	NR	9	[11]
1.32, rod	0.26	NR	Horizontal	460-464	NR	19.6~22.2	[11]
2.36, rod	0.50	NR	Horizontal	440	NR	2.6	[12]
7.64, rod	1.79	NR	Horizontal	445	NR	NR	[13]
0.86, dot	0.79	NR	Vertical	448	1,070.40 (10 V)	6.21	[14]
2.17, fin	2.28	91.3	Vertical	448	8,640 (5 V)	9.1	Our works

*NR Non-reported

Supplementary Table 2 | Comparison for micro-LED electric properties in sizes below $10 \mu\text{m}^2$

	Dielectric constant (ϵ_0)	Electrical conductivity ($S\ m^{-1}$)	Reference
n-GaN	8.9	20×10^3	[7]
p-GaN	8.9	2.38×10^{-3}	[15]
ITO	3.2	10^6	[15]
SiO ₂	3.9	1×10^{-12}	[16]
Acetone	20.7	20×10^{-6}	[17]

Supplementary Table 3 | Physical properties of materials used in FEM simulation

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